



General description

These surge protection diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

Features and benefits

- Bidirectional ESD protection of one line
- Reverse stand-off voltage: 20V Max
- Low leakage current: nA Level
- Response time is typically < 1 ns
- Low clamping voltage: $V_C = 30V @ I_{PP} = 8 A$ (TYP)
- ESD Protection: 30kV(air)/ 30kV(contact) (IEC61000-4-2)
- RoHS compliant

Application information

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers

Ordering information

Device	Package	Packaging	Reel Size
SLSD20C	SOD323	3000/Tape & Reel	7 Inch

Schematic & Pin configuration

Simplified outline	Graphic symbol

Maximum Ratings ($T_{OP} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

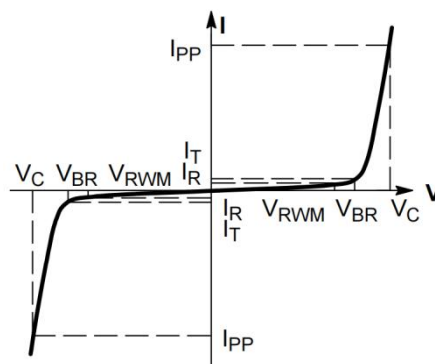
Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p = 8/20\text{ }\mu\text{s}$)	P_{PPM}	256	W
Peak Pulse Current($t_p = 8/20\text{ }\mu\text{s}$)	I_{PPM}	8	A
ESD voltage IEC 61000-4-2 (air discharge)	V_{ESD}	30	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V_{ESD}	30	kV
Maximum lead temperature for soldering during 10s	T_L	260	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^{\circ}\text{C}$
Operating Temperature Range	T_{OP}	-40 to +125	$^{\circ}\text{C}$

Electrical Characteristics ($T_{OP} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

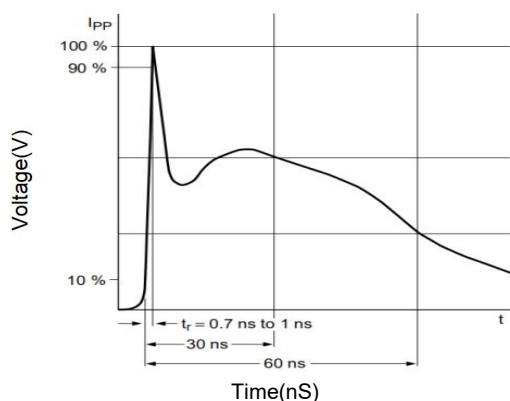
Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V_{RWM}	--	--	20.0	V	
Breakdown Voltage	V_{BR}	21.5	23	25.0	V	$I_T=1\text{mA}$
Leakage Current I_{Leak}	I_R	--	--	100	nA	$V_{RWM}=20\text{V}$
Clamping Voltage	V_C	--	24	--	V	$I_{PP}=1\text{A}, t_p=8/20\mu\text{s}$
		--	30	32		$I_{PP}=8\text{A}, t_p=8/20\mu\text{s}$
Junction Capacitance	C_J	--	26	30	pF	$V_R=0\text{V}, f=1\text{MHz}$
Junction Capacitance	C_J	--	13	15	pF	$V_R=20\text{V}, f=1\text{MHz}$

Portion Electronics Parameter

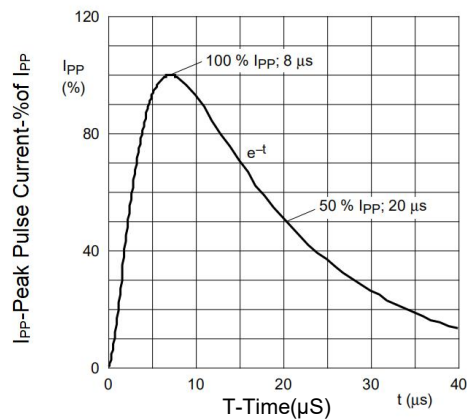
Symbol	Parameter
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	VBR Test Current



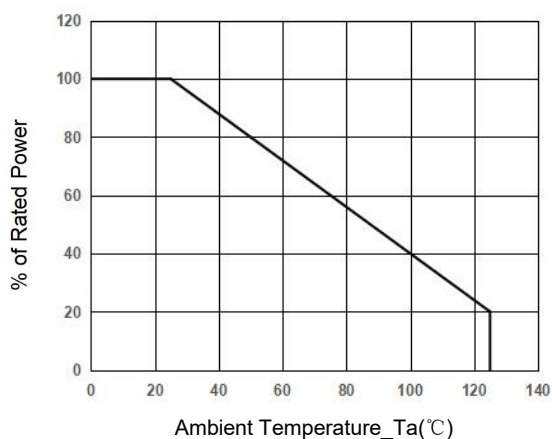
Typical Performance Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise Specified)



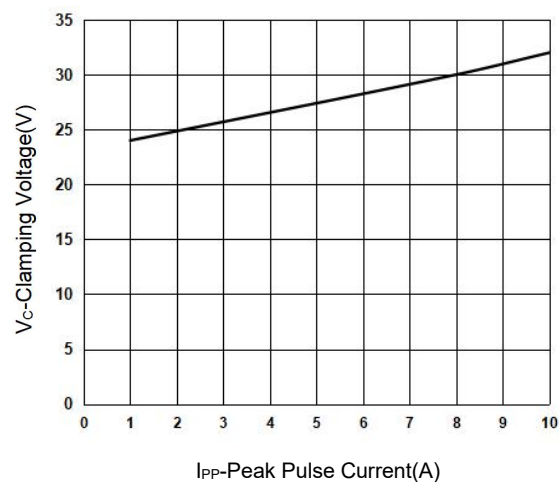
IEC61000-4-2 Pulse Waveform



IEC61000-4-5 8X20µs Pulse Waveform



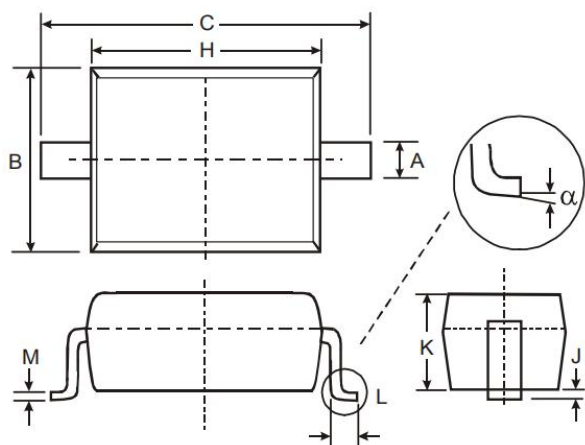
Power Derating Curve



Clamping Voltage vs. Peak Pulse Current

Package Outline Dimensions

SOD323



SYMBOL	MILLIMETERS	
	MIN	MAX
A	0.25	0.35
B	1.20	1.40
C	2.40	2.70
H	1.60	1.80
J	0.01	0.15
K	0.70	0.90
L	0.20	0.40
M	0.08	0.15
α	0°	8°